

FAMILY OF LOW-POWER WIDE BANDWIDTH SINGLE SUPPLY OPERATIONAL AMPLIFIERS WITH AND WITHOUT SHUTDOWN

FEATURES

- Rail-To-Rail Output
- V_{ICR} Includes Ground
- Gain-Bandwidth Product . . . 9 MHz
- Supply Current . . . 730 μA/Channel
- Single, Duals, and Quad Versions
- Ultralow Power Down Mode I_{DD(SHDN}) = 4 μA/Channel
- Specified Temperature Range
 -40°C to 125°C . . . Industrial Grade
- Supply Voltage Range . . . 2.7 V to 5.5 V
- Ultrasmall Packaging
 5 or 6 Pin SOT-23 (TLV2630/1)
 8 or 10 Pin MSOP (TLV2632/3)
- Universal Op-Amp EVM (See SLOU060 for More Information)

Operational Amplifier



DESCRIPTION

The TLV263x single supply operational amplifiers provide rail-to-rail output with an input range that includes ground. The TLV263x takes the minimum operating supply voltage down to 2.7 V over the extended industrial temperature range (–40°C to 125°C) while adding the rail-to-rail output swing feature. The TLV263x also provides a 9 MHz gain-bandwidth product from only 730 μA of supply current. The maximum recommended supply voltage is 5.5 V, which, when coupled with a 2.7-V minimum, allows the devices to be operated from lithium ion cells.

The combination of wide bandwidth, low noise, and low distortion makes it ideal for high speed and high resolution data converter applications. The ground input range allows it to directly interface to ground rail referred systems.

All members are available in PDIP and SOIC with the singles in the small SOT-23 package, duals in the MSOP, and quads in the TSSOP package.

The 2.7-V operation makes it compatible with Li-Ion powered systems and the operating supply voltage range of many micro-power microcontrollers available today including TI's MSP430.

AMPLIFIER SELECTION TABLE

DEVICE	V _{DD} [V]	I _{DD} /ch [μΑ]	V _{ICR} [V]	GBW [MHz]	SLEW RATE [V/μs]	V _{n,} 1 <u>kH</u> z [nV/√Hz]	lO [mA]
OPAx343	2.5-5.5	850	-0.3 to $V_{DD} + 0.3$	5.5	6	25	40
OPAx743	3.5–12	1100	-0.1 to V _{DD} + 0.1	7	10	30	20
TLV278x	1.8–3.6	650	-0.2 to $V_{DD} + 0.2$	8	5	9	10
TLV263x	2.7-5.5	730	GND to V _{DD} – 1	9	9.5	50	28
TLV262x	2.7-5.5	750	1 V to V _{DD} + 0.2	11	10	27	28
OPAx353	2.7-5.5	8000	-0.1 to V _{DD} + 0.1	44	22	7	40



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE	PACKAGE CODE	SYMBOL	SPECIFIED TEMPERATURE RANGE	ORDER NUMBER	TRANSPORT MEDIA
Single with Shi	utdown					
TLV2630ID	SOIC-8	D	_		TLV2630ID TLV2630IDR	Tube Tape and Reel
TLV2630IDBV	SOT-23-6	DBV	VAYI	−40°C to 125°C	TLV2630IDBVR† TLV2630IDBVT‡	Tape and Reel
TLV2630IP	DIP-8	Р	_		TLV2630IP	Tube
Single without	Shutdown					
TLV2631ID	SOIC-8	D	_		TLV2631ID TLV2631IDR	Tube Tape and Reel
TLV2631IDBV	SOT-23-5	DBV	VAZI	−40°C to 125°C	TLV2631IDBVR [†] TLV2631IDBVT [‡]	Tape and Reel
TLV2631IP	DIP-8	Р	_		TLV2631IP	Tube
Dual without S	hutdown					
TLV2632ID	SOIC-8	D	_		TLV2632ID TLV2632IDR	Tube Tape and Reel
TLV2632IDGK	MSOP-8	DGK	AKG	−40°C to 125°C	TLV2632IDGK TLV2632IDGKR	Tube Tape and Reel
TLV2632IP	DIP-8	Р	_		TLV2632IP	Tube
Dual with Shut	down					
TLV2633ID	SOIC-14	D	1		TLV2633ID TLV2633IDR	Tube Tape and Reel
TLV2633IDGS	MSOP-10	DGS	AKK	−40°C to 125°C	TLV2633IDGS TLV2633IDGSR	Tube Tape and Reel
TLV2633IN	DIP-14	N	_		TLV2633IN	Tube
Quad without S	Shutdown					
TLV2634ID	SOIC-14	D	_		TLV2634ID TLV2634IDR	Tube Tape and Reel
TLV2634IN	DIP-14	N	_	-40°C to 125°C	TLV2634IN	Tube
TLV2634IPW	TSSOP-14	PW	_		TLV2634IPW TLV2634IPWR	Tube Tape and Reel
Quad with Shu	tdown					
TLV2635ID	SOIC-16	D	_		TLV2635ID TLV2635IDR	Tube Tape and Reel
TLV2635IN	DIP-16	N	_	-40°C to 125°C	TLV2635IN	Tube
TLV2635IPW	TSSOP-16	PW	_		TLV2635IPW TLV2635IPWR	Tube Tape and Reel

[†] The SOT23 package devices are only available taped and reeled. The R Suffix denotes quantities (3,000 pieces per reel).



[‡] The **T** Suffix denotes smaller quantities (250 pieces per mini-reel).

^{1.} For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{DD} (see Note 1)	6 V
Differential input voltage, V _{ID}	
Input voltage range, V _I (see Note 1)	
Input current, I _I (any input)	±10 mA
Output current, IO	±40 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A : I-suffix	–40°C to 125°C
Maximum junction temperature, T,J	150°C
Storage temperature range, T _{stq}	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

NOTE 2: All voltage values, except differential voltages, are with respect to GND.

recommended operating conditions

		MIN	MAX	UNIT
Complex of the rest V	Single supply	2.7	5.5	
Supply voltage, V _{DD}	Split supply	±1.35	±2.75	V
Common-mode input voltage range, VICR		GND	V _{DD} -1	V
Operating free-air temperature, TA	I-suffix	-40	125	°C
Shutdown on/off voltage level‡	V _{IL}		0.4	V
Silutuowii oli/oli voltage level+	ViH	2	_	V

[‡] Relative to GND.

electrical characteristics at specified free-air temperature, $V_{DD} = 2.7 \text{ V}$, 5 V (unless otherwise noted)

dc performance

	PARAMETER	TEST CONDITION	ONS	TA	MIN	TYP	MAX	UNIT
						250	3500	.,
	land effect voltage			Full range			4500	μV
VIO	Input offset voltage	$V_{IC} = V_{DD}/2,$ $V_{O} = V_{DD}/2$	TIVOCOAIE	25°C		250	4200	/
		$V_O = V_{DD}/2$	TLV2634/5	Full range			5200	μV
αΛΙΟ	Temperature coefficient of input offset voltage			25°C		3		μV/°C
			V== - 2.7.V	25°C	76	100		
CMDD	Common mode rejection ratio	\\\- CND to \/== 4 \/	$V_{DD} = 2.7 V$	Full range	67] _ [
CMRR	Common-mode rejection ratio	$V_{IC} = GND \text{ to } V_{DD}-1 \text{ V}$	V 5.V	25°C	77	100		dB
			$V_{DD} = 5 V$	Full range	74			
	Large-signal differential voltage	.		25°C	90	100		9
AVD	amplification	$R_L = 2 k\Omega$, $V_{O(PP)} = V_D$	D-1 V	Full range	82			dB



[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

electrical characteristics at specified free-air temperature, V_{DD} = 2.7 V, 5 V (unless otherwise noted) (continued)

input characteristics

PARAMETER		TEST CONDITIONS	T _A †	MIN	TYP	MAX	UNIT
1	land affect account		25°C		1	50	
IIO	Input offset current	$V_{IC} = V_{DD}/2$,	Full range			100	A
	Land bin assumed	$V_{IC} = V_{DD}/2,$ $V_{O} = V_{DD}/2$	25°C		1	50	рA
IIB	Input bias current		Full range			200	
r _{i(d)}	Differential input resistance		25°C		1000		GΩ
C _{i(c)}	Common-mode input capacitance	f = 1 kHz	25°C		12		pF

[†] Full range is -40°C to 125°C for the I-suffix.

output characteristics

	PARAMETER	TEST CONDITION	NS	T _A †	MIN	TYP	MAX	UNIT	
				25°C	2.6	2.67			
			$V_{DD} = 2.7 V$	Full range	2.55				
		$V_{IC} = V_{DD}/2$, $I_{OH} = -1 \text{ mA}$	V _{DD} = 5 V	25°C	4.92	4.98			
.,	LPak laval autout valtana			Full range	4.9			.,	
VOH	High-level output voltage		V 0.7.V	25°C	2.25	2.43		V	
		$V_{IC} = V_{DD}/2$, $I_{OH} = -10 \text{ mA}$	$V_{DD} = 2.7 V$	Full range	2.15				
			V 5 V	25°C	4.7	4.8			
			$V_{DD} = 5 V$	Full range	4.65				
			V 0.7.V	25°C		0.03	0.1	mV	
		V V (0 1 4 3 4	$V_{DD} = 2.7 V$	Full range			0.15		
		$V_{IC} = V_{DD}/2$, $I_{OL} = 1 \text{ mA}$	Vpp = 5 V	25°C		0.025	0.08		
.,	Lavolaval autout valtana		$V_{DD} = 5 V$	Full range			0.1		
VOL	Low-level output voltage		Vpp = 2.7.V	25°C		0.26	0.45		
			$V_{DD} = 2.7 V$	Full range			0.47		
		$V_{IC} = V_{DD}/2$, $I_{OL} = 10 \text{ mA}$	V 5.V	25°C		0.2	0.3		
			$V_{DD} = 5 V$	Full range			0.35		
		V _{DD} = 2.7 V,	Sourcing			14			
1	Outrout assument	$V_O = 0.5 \text{ V from rail}$	Sinking	2500		19		A	
IO	Output current	V _{DD} = 5 V,	Sourcing	25°C		28		mA	
		$V_O = 0.5 \text{ V from rail}$	Sinking		28				
		Coursing	V _{DD} = 2.7 V			50			
	Ob ant aims it as to start as are and	Sourcing	V _{DD} = 5 V	0500		95		A	
los	Short-circuit output current	Cialian	V _{DD} = 2.7 V	25°C		50		mA	
		Sinking	V _{DD} = 5 V	7 l		95			

[†] Full range is –40°C to 125°C for the I-suffix.

power supply

PARAMETER		TEST CONDITIONS		T _A †	MIN	TYP	MAX	UNIT
	Oursele constant (constant)		25°C		730	1000		
IDD	Supply current (per channel)	$V_O = V_{DD}/2,$	SHDN = V _{DD}	Full range			1350	μΑ
DCDD	Supply voltage rejection ratio	$V_{DD} = 2.7 \text{ V to } 5.5 \text{ V},$	Nalaad	25°C	70	90		70
PSRR	$(\Delta V_{DD} / \Delta V_{IO})$	$V_{IC} = V_{DD}/2$	No load	Full range	65			dB

[†] Full range is –40°C to 125°C for the I-suffix.



electrical characteristics at specified free-air temperature, V_{DD} = 2.7 V, 5 V (unless otherwise noted) (continued)

dynamic performance

	PARAMETER	TEST CONDI	TIONS	T _A †	MIN	TYP	MAX	UNIT
GBWP	Gain-bandwidth product	$R_L = 2 k\Omega$, $C_L = 10 pF$,	f = 10 kHz			9		MHz
00.	Positive slew rate at unity gain $R_{L} = 2 \text{ kO} \cdot C_{L} = 50 \text{ pF}$ $V_{DD} = 2.7 \text{ V},$ $V_{O(PP)} = 1.7 \text{ V}$				6		\// -	
SR+ Positive slew rate at unity gain	$R_L = 2 k\Omega$, $C_L = 50 pF$	$V_{DD} = 5 \text{ V},$ $V_{O(PP)} = 3.5 \text{ V}$			6		V/μs	
0.0	No setting all control of the first	D 010 0 50 F	$V_{DD} = 2.7 \text{ V},$ $V_{O(PP)} = 1.7 \text{ V}$	25°C		10		V/μs
SR- Negative slew rate at unity	Negative slew rate at unity gain	$R_L = 2 k\Omega$, $C_L = 50 pF$	V _{DD} = 5 V, V _{O(PP)} = 3.5 V			9.5		V/μs
φm	Phase margin	D 010	0 40 - 5			50		0
	Gain margin	$R_L = 2 k\Omega$,	$C_L = 10 pF$			20		dB

[†] Full range is –40°C to 125°C for the I-suffix.

noise/distortion performance

PARAMETER		TEST CONDITIO	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
			A _V = 1		0.003%				
THD + N Total harmonic distortion plus noise		$V_{O(PP)} = V_{DD}/2,$ $R_1 = 2 k\Omega, f = 10 kHz$	A _V = 10		0.02%				
			A _V = 100	0500		0.095%			
	Emphysical investoration and the ma	f = 1 kHz		25°C		50		nV/√ Hz	
Vn	Equivalent input noise voltage	f = 10 kHz				30		nv/√Hz	
In	Equivalent input noise current	f = 1 kHz				0.9		fA/√Hz	

shutdown characteristics

PARAMETER		TEST CONDITIONS		T _A †	MIN	TYP	MAX	UNIT
1	Supply current, per channel in shutdown	SHDN = 0.4 V		25°C		4	17	^
IDD(SHDN)	mode (TLV2630, TLV2633, TLV2635)			Full range			19	μΑ
4	A many life out to the company time of		V _{DD} = 2.7 V			4.5		
t(on)	Amplifier turnon time‡	$R_L = 2 k\Omega$, $C_L = 10 pF$	V _{DD} = 5 V	25°C		1.5		μs
t(off)	Amplifier turnoff time‡	о 10 рі				200		ns

[†] Full range is –40°C to 125°C for the I-suffix.



[‡] Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.

DISSIPATION RATING TABLE

PACKAGE	(∘C/M) ⊝JC	[⊝] JA (°C/W)	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ Power rating	T _A = 125°C POWER RATING
D (8)	38.3	176	710 mW	142 mW
D (14)	26.9	122.3	1022 mW	204.4 mW
D (16)	25.7	114.7	1090 mW	218 mW
DBV (5)	55	324.1	385 mW	77.1 mW
DBV (6)	55	294.3	425 mW	85 mW
DGK (8)	54.2	259.9	481 mW	96.1 mW
DGS (10)	54.1	259.7	485 mW	97 mW
N (14, 16)	32	78	1600 mW	320.5 mW
P (8)	41	104	1200 mW	240.4 mW
PW (14)	29.3	173.6	720 mW	144 mW
PW (16)	28.7	161.4	774 mW	154.9 mW

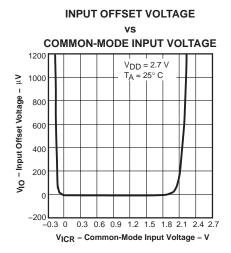
TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V _{IO}	Input offset voltage	vs Common-mode input voltage	1, 2
CMRR	Common-mode rejection ratio	vs Frequency	3
VOH	High-level output voltage	vs High-level output current	4, 6
VOL	Low-level output voltage	vs Low-level output current	5, 7
l _{DD}	Supply current	vs Supply voltage	8
l _{DD}	Supply current	vs Free-air temperature	9
PSRR	Power supply rejection ratio	vs Frequency	10
A _{VD}	Differential voltage amplification & phase	vs Frequency	11
		vs Supply voltage	12
	Gain-bandwidth product	vs Free-air temperature	13
SR	Olemente	vs Supply voltage	14
	Slew rate	vs Free-air temperature	15, 16
φm	Phase margin	vs Load capacitance	17
V _n	Equivalent input noise voltage	vs Frequency	18
	Crosstalk	vs Frequency	19
	Voltage-follower large-signal pulse response		20
	Voltage-follower small-signal pulse response		21
IDD(SHDN)	Shutdown supply current	vs Free-air temperature	22
IDD(SHDN)	Shutdown supply current	vs Supply voltage	23
IDD(SHDN)	Shutdown supply current/output voltage	vs Time	24



INPUT OFFSET VOLTAGE



COMMON-MODE INPUT VOLTAGE

1200

VDD = 5 V

TA = 25° C

98 800

400

-200

-0.5 0 0.5 1 1.5 2 2.5 3 3.5 4 4.5 5

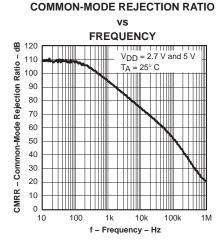
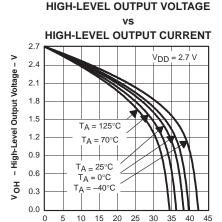


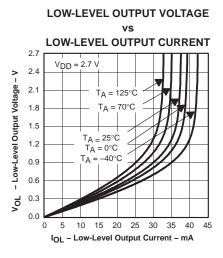
Figure 1

Figure 2

VICR - Common-Mode Input Voltage - V

Figure 3





HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT 5.0 V_{DD} = 5 V - High-Level Output Voltage - V 4.0 3.5 T_A = 125°C 3.0 T_A = 70°C 2.5 T_{A =} 25°C 2.0 $T_A = 0$ °C 1.5 T_A = −40°C 1.0 Λон 0.5 0.0 20 30 40 50 60 70 80 IOH - High-Level Output Current - mA

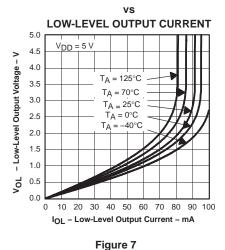
LOW-LEVEL OUTPUT VOLTAGE

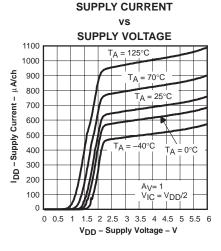
IOH - High-Level Output Current - mA

Figure 4

Figure 5

Figure 6





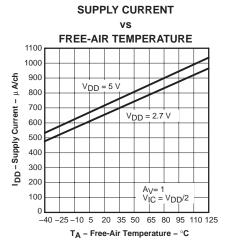


Figure 9

re 7 Figure 8



POWER SUPPLY REJECTION RATIO

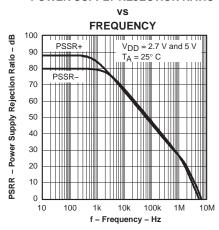


Figure 10

DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE

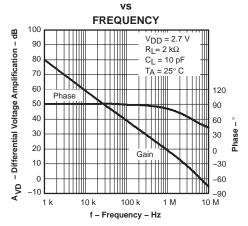


Figure 11

GAIN-BANDWIDTH PRODUCT

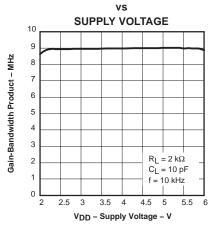


Figure 12

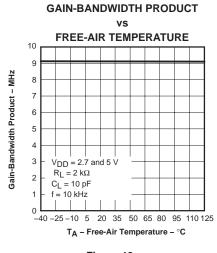
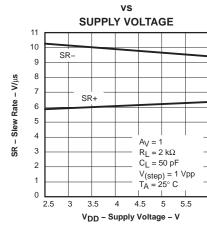


Figure 13



SLEW RATE

Figure 14

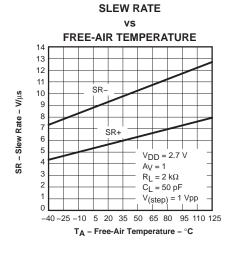


Figure 15

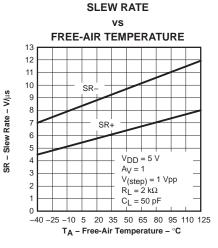


Figure 16

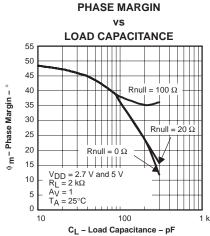


Figure 17



EQUIVALENT INPUT NOISE VOLTAGE

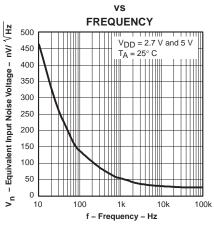


Figure 18

VOLTAGE-FOLLOWER LARGE-SIGNAL

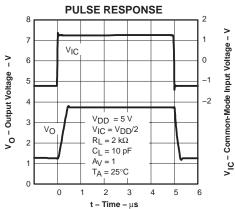


Figure 20

SHUTDOWN SUPPLY CURRENT

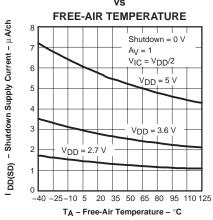


Figure 22

FREQUENCY $V_{DD} = 2.7 \text{ V}$ and 5 V $R_L = 2 \text{ k}\Omega$

CROSSTALK

vs

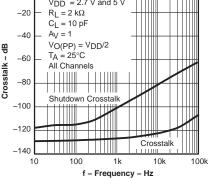


Figure 19

VOLTAGE-FOLLOWER SMALL-SIGNAL

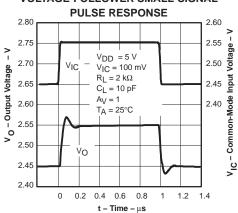


Figure 21

SHUTDOWN SUPPLY CURRENT

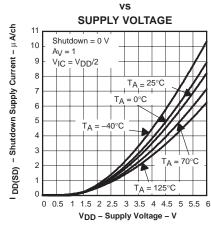
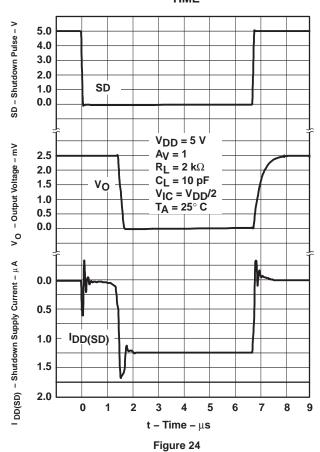


Figure 23

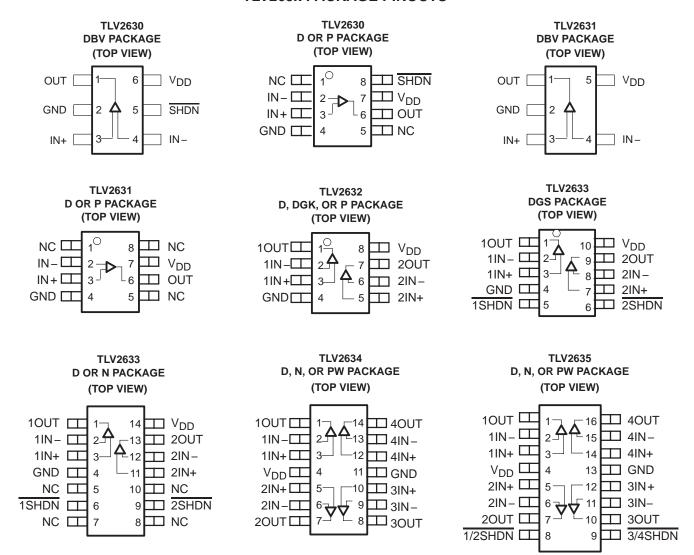


SHUTDOWN SUPPLY CURRENT / OUTPUT VOLTAGE

TIME



TLV263x PACKAGE PINOUTS



NC - No internal connection





24-Aug-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TLV2630IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAYI	Samples
TLV2631IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAZI	Samples
TLV2631IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAZI	Samples
TLV2632IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AKG	Samples
TLV2632IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26321	Samples
TLV2634ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26341	Samples
TLV2634IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26341	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

24-Aug-2014

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2630IDBVR	SOT-23	DBV	6	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2631IDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2631IDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2632IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2632IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2634IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2630IDBVR	SOT-23	DBV	6	3000	182.0	182.0	20.0
TLV2631IDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2631IDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2632IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2632IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2634IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4073253/P





SMALL OUTLINE TRANSISTOR



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC MO-178.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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